NSN 5961-01-212-7308

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-212-7308 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.230 inches **End Application:** Satellite communications set, an/wsc- (v) 9 **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-72 **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 15.0 collector to base voltage/static/emitter open and 12.0 collector to emitter voltage/static/base open and 1.5 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 35.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 200.0 milliwatts small-signal input power, common-collector preset **Transfer Ratio:** 50.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Static discharge; junction pattern arrangement: npn **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life:

Demilitarization: No

Unit Of Measure:

N/a

NSN 5961-01-212-7308 Transistor - Page 2 of 2



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